RL1601 THRU RL1607

GLASS PASSIVATED SILICON RECTIFIER

REVERSE VOLTAGE: FORWARD CURRENT:

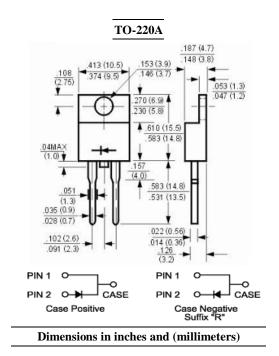
50 to 1000 VOLTS 16.0 AMPERE

FEATURES

- \cdot Low forward voltage drop
- · High current capability
- \cdot High capability
- \cdot High surge current capability

MECHANICAL DATA

Case: Molded plastic, TO-220A Epoxy: UL 94V-O rate flame retardant Terminals: Leads solderable per MIL-STD-202 method 208 guaranteed Polarity: As marked Mounting position: Any Weight: 0.08ounce, 2.24gram



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Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, $60H_Z$, resistive or inductive load.

For capacitive load, derate current by 20%.

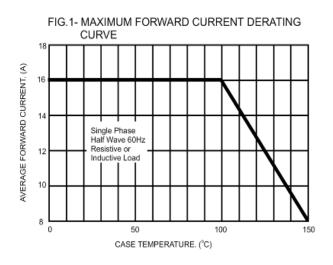
	Symbols	RL1601	RL1602	RL1603	RL1604	RL1605	RL1606	RL1607	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current	т	16.0							Amp
.375''(9.5mm) Lead Length at T _C =100℃	I _(AV)								
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I _{FSM} 250							Amp	
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage	V _F	1.1							Volts
at 16.0A DC and 25°C	۷F								
Maximum Reverse Current at T _C =25°C	т	10.0							
at Rated DC Blocking Voltage T _C =125°C	I _R				250	250			uAmp
Typical Junction Capacitance (Note 1)	CJ	100							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	2							°C/W
Operating and Storage Temperature Range	T _J , Tstg				-55 to +15	0			ç

NOTES:

1- Measured at 1 MH_Z and applied reverse voltage of 4.0 VDC.

2- Thermal Resistance from Junction to Case Mounted on Heatsink.

RATINGS AND CHARACTERISTIC CURVES



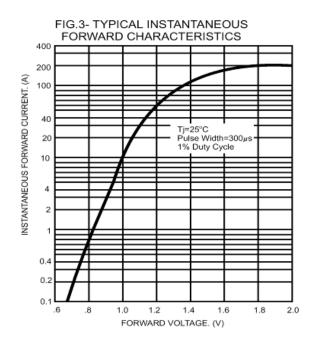
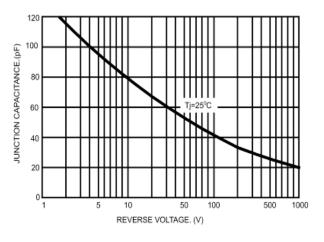


FIG.5- TYPICAL JUNCTION CAPACITANCE



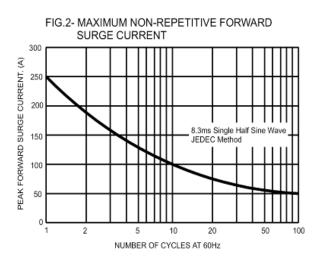


FIG.4- TYPICAL REVERSE CHARACTERISTICS

